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October 21, 2004

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Re:

Applicant:

Yi Ding

Assignee:

Mosel Vitelic, Inc.

Title:

Fabrication Of Gate Dielectric In Nonvolatile Memories

In Which A Memory Cell Has Multiple Floating Gates

Application No.:

10/632,154

Filed:

July 30, 2003

Examiner:

Nguyen, Khiem D.

Group Art:

2823

Docket No.:

M-15230 US

Confirmation No.:

1878

Dear Sir:

Transmitted herewith are the following documents in the above-identified application:

- (1) Return Receipt Postcard;
- (2) This Transmittal Letter (1 page in duplicate); and
- (3) Amendment (8 pages).

No additional fee is required.

The fee has been calculated as shown below:

CLAIMS AS AMENDED

	Claims Remainin <u>After Amendmer</u>	•	Highest No. Previously <u>Paid For</u>		Present Extra		Rate		Additional Fee
Total Cla	ms 26	Minus	29	=	0	x	\$18.00	\$	0.00
Independe Claims	ent 2	Minus	3	=	0	х	\$88.00	\$	0.00
☐ Fe	e of for the first to pendent claims per appl	filing of one or ication	more multiple					\$	
Fee for Request for Extension of Time								\$	0.00
	Total additiona	l fee for this A	mendment:					\$	
Conditional Petition for Extension of Time: If an extension of time is required for timely filing of the enclosed document(s) after all papers filed with this transmittal have been considered, an extension of time is hereby requested.									
☐ Ple	Please charge our Deposit Account No. 50-2257 in the amount of							\$	0.00
	Also, charge any additional fees required and credit any overpayment to our Deposit Account No. 50-2257								
						7	otal:	\$	0.00

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on October 21, 2004.

Attorney for Applicant(s)

Date of Signature

Respectfully submitted,
Michael Shewker

Michael Shenker Attorney for Applicants Reg. No. 34,250



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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First Named Inventor:

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AMENDMENT

Dear Sir:

In reply to the Office Action dated July 27, 2004, please amend this application as shown below.

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Amendment to Claims	
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